

Seven Segment Displays for High Light Ambient Conditions

Technical Data

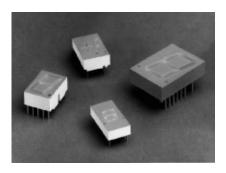
HDSP-3530/-3730/-5530/ -3900 Series HDSP-4030/-4130/-5730/ -4200 Series

Features

- High Light Output
 Typical Intensities of Up to 7.0
 mcd/seg at 100 mA pk 1 of 5
 Duty Factor
- Capable of High Current Drive
 Excellent for Long Digit String Multiplexing
- Four Character Sizes 7.6 mm, 10.9 mm, 14.2 mm, and 20.3 mm
- Choice of Two Colors
 High Efficiency Red
 Yellow
- Excellent Character
 Appearance
 Evenly Lighted Segments
 Wide Viewing Angle
 Gray Body for Optimum
 Contrast
- Categorized for Luminous Intensity; Yellow
 Categorized for Color
 Use of Like Categories Yields a Uniform Display
- IC Compatible
- Mechanically Rugged

Description

The HDSP-3530/-3730/-5530/ -3900 and HDSP-4030/-4130/ -5730/-4200 are 7.6 mm, 10.9 mm/14.2 mm/20.3 mm high efficiency red and yellow displays designed for use in high light ambient condition. The four sizes of displays allow for viewing distances at 3, 6, 7, and 10 meters. These seven segment displays utilize large junction high efficiency LED chips made from GaAsP on a transparent GaP substrate. Due to the large junction area, these displays can be driven at high peak current levels needed for high ambient conditions or many character multiplexed operation.



These displays have industry standard packages, and pin configurations and ± 1 overflow display are available in all four sizes. These numeric displays are ideal for applications such as Automotive and Avionic Instrumentation, Point of Sale Terminals, and Gas Pump.

3-42 5964-6374E

Devices

Part No. HDSP-	Color	Description	Package Drawing
3530	High Efficiency Red	7.6 mm Common Anode Left Hand Decimal	A
3531		7.6 mm Common Anode Right Hand Decimal	В
3533		7.6 mm Common Cathode Right Hand Decimal	C
3536		7.6 mm Universal Overflow ± 1 Right Hand Decimal	D
4030	Yellow	7.6 mm Common Anode Left Hand Decimal	A
4031		7.6 mm Common Anode Right Hand Decimal	В
4033		7.6 mm Common Cathode Right Hand Decimal	C
4036		7.6 mm Universal Overflow \pm 1 Right Hand Decimal	D
3730	High Efficiency Red	10.9 mm Common Anode Left Hand Decimal	Е
3731		10.9 mm Common Anode Right Hand Decimal	F
3733		10.9 mm Common Cathode Right Hand Decimal	G
3736		10.9 mm Universal Overflow ± 1 Right Hand Decimal	Н
4130	Yellow	10.9 mm Common Anode Left Hand Decimal	Е
4131		10.9 mm Common Anode Right Hand Decimal	F
4133		10.9 mm Common Cathode Right Hand Decimal	G
4136		10.9 mm Universal Overflow ± 1 Right Hand Decimal	Н
5531	High Efficiency Red	14.2 mm Common Anode Right Hand Decimal	I
5533		14.2 mm Common Cathode Right Hand Decimal	J
5537		14.2 mm Overflow ± 1 Common Anode	K
5538		14.1 mm Overflow ± 1 Common Cathode	L
5731	Yellow	14.2 mm Common Anode Right Hand Decimal	I
5733		14.2 mm Common Cathode Right Hand Decimal	J
5737		14.2 mm Overflow ± 1 Common Anode	K
5738		14.1 mm Overflow ± 1 Common Cathode	L
3900	High Efficiency Red	20.3 mm Common Left Hand Decimal	M
3901		20.3 mm Common Anode Right Hand Decimal	N
3903		20.3 mm Common Cathode Right Hand Decimal	О
3905		20.3 mm Common Cathode Left Hand Decimal	P
3906		20.3 mm Universal Overflow ± 1 Right Hand Decimal	Q
4200	Yellow	20.3 mm Common Left Hand Decimal	M
4201		20.3 mm Common Anode Right Hand Decimal	N
4203		20.3 mm Common Cathode Right Hand Decimal	О
4205		20.3 mm Common Cathode Left Hand Decimal	P
4206		20.3 mm Universal Overflow ± 1 Right Hand Decimal	Q

Note: Universal pinout brings the anode and cathode of each segment's LED out to separate pins. See internal diagrams D and H.

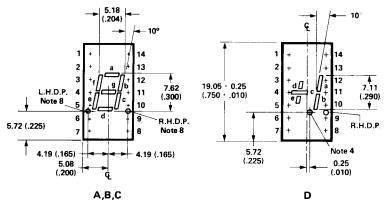
Absolute Maximum Ratings (All Products)

Average Power per Segment or DP (T _A = 25°C)	105 mW
Peak Forward Current per Segment or DP (T _A = 25°C)	1.135 mA (Pulse Width = $0.16 ms$)
DC Forward Current per Segment ^[2] or DP ($T_A = 25$ °C)	40 mA
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	40°C to +85°C
Reverse Voltage per Segment or DP	5.0 V
Lead Solder Temperature (1.59 mm [1/16 inch] below seating plane)	260°C for 3 sec

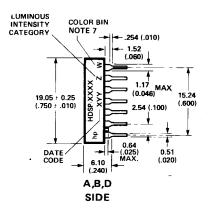
Notes:

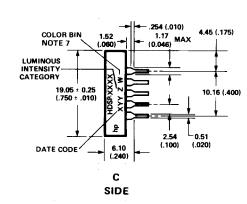
- 1. See Figure 1 to establish pulsed operating conditions 2. Derate maximum DC current above $\rm T_A=25\,^\circ\!C$ at 0.50 mA/°C per segment, see Figure 2.

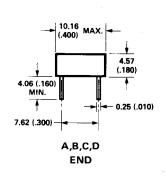
Package Dimensions (HDSP-3530/-4030 Series)



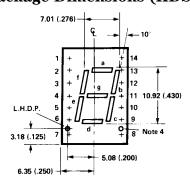
	FUNCTION					
	Α	В	С	D		
	-3530/-4030	-3531/-4031	-3533/-4033	-3536/-4036		
1	CATHODE-a	CATHODE-a	CATHODE ^[6]	ANODE-d		
2	CATHODE-f	CATHODE-f	ANODE-f	NO PIN		
3	ANODE[3]	ANODE[3]	ANODE-g	CATHODE-d		
4	NO PIN	NO PIN	ANODE-e	CATHODE-c		
5	NO PIN	NO PIN	ANODE-d	CATHODE-e		
6	CATHODE-dp	NO CONN.[5]	CATHODE ^[6]	ANODE-e		
7	CATHODE-e	CATHODE-e	ANODE-dp	ANODE-c		
8	CATHODE-d	CATHODE-d	ANODE-c	ANODE-dp		
9	NO CONN.[5]	CATHODE-dp	ANODE-b	NO PIN		
10	CATHODE-c	CATHODE-c	ANODE-a	CATHODE-dp		
11	CATHODE-g	CATHODE-g		CATHODE-b		
12	NO PIN	NO PIN		CATHODE-a		
13	CATHODE-b	CATHODE-b		ANODE-a		
14	ANODE[3]	ANODE[3]		ANODE-b		



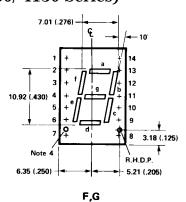


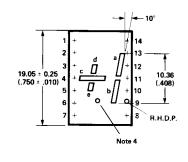


Package Dimensions (HDSP-3730/-4130 Series)



Ε

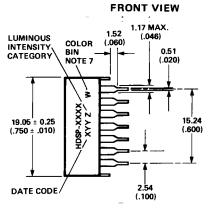




Н

-	12.70 (.500) MAX.		<u> </u>
		5.33 (.210)	6.35 (.250)
4.06 (.160) MIN.			1
Ī		0.25 (.010)	
7.62 (.300)	-		

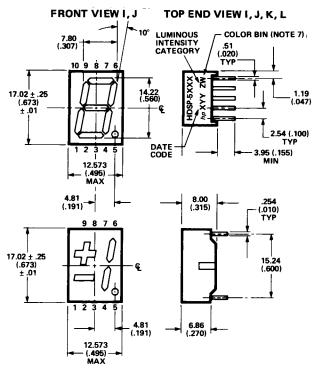
END VIEW



SIDE VIEW

	FUNCTION					
PIN	E -3730/-4130	F -3731/-4131	G -3733/-4133	H -3736/-4136		
1	CATHODE-a	CATHODE-a	ANODE-a	. CATHODE-d		
2	CATHODE-f	CATHODE-f	ANODE-f	ANODE-d		
3	ANODE [3]	ANODE[3]	CATHODE [6]	NO PIN		
4	NO PIN	NO PIN	NO PIN	CATHODE-c		
5	NO PIN	NO PIN	NO PIN	CATHODE-e		
6	CATHODE-dp	NO CONN.[5]	NO CONN.[5]	ANODE-e		
7	CATHODE-e	CATHODE-e	ANODE-e	ANODE-¢		
8	CATHODE-d	CATHODE-d	ANODE-d	ANODE-dp		
9	NO CONN. [5]	CATHODE-dp	ANODE-dp	CATHODE-d		
10	CATHODE-c	CATHODE-c	ANODE-c	CATHODE-b		
11	CATHODE-g	CATHODE-g	ANODE-g	CATHODE-a		
12	NO PIN	NO PIN	NO PIN	NO PIN		
13	CATHODE-b	CATHODE-b	ANODE-b	ANODE-a		
14	ANODE [3]	ANODE[3]	CATHODE [6]	ANODE-b		

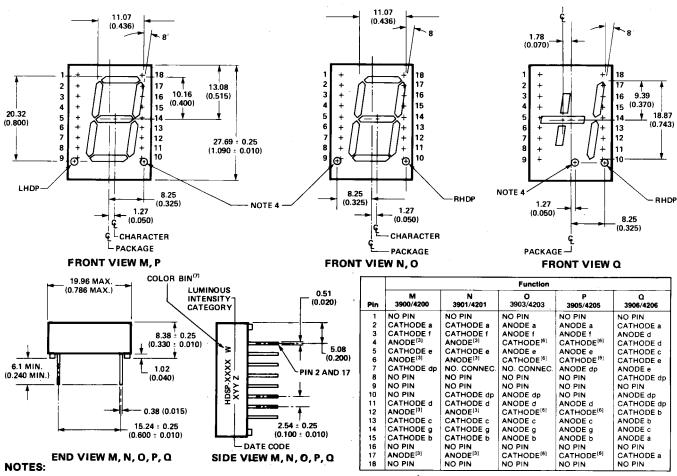
Package Dimensions (-5530/-5730 Series)



PIN	FUNCTION					
FIN	I 5531	I 5531 J 5533		L 5538		
1	CATHODE e	ANODE e	CATHODE c	ANODE c		
2	CATHODE d	ANODE d	ANODE c, d	CATHODE c, d		
3	ANODE(3)	CATHODE (6)	CATHODE b	ANODE b		
4	CATHODE c	ANODE c	ANODE a, b	CATHODE a, b, DP		
5	CATHODE DP	ANODE DP	CATHODE DP	ANODE DP		
6	CATHODE b	ANODE b	CATHODE a	ANODE a		
7	CATHODE a	ANODE a	ANODE a, b, DP	CATHODE a, b, DP		
8	ANODE ⁽³⁾	CATHODE (6)	ANODE c, d	CATHODE c, d		
9	CATHODE f	ANODE f	CATHODE d	ANODE d		
10	CATHODE g	ANODE g	NO PIN ⁽⁵⁾	NO PIN ⁽⁵⁾		

FRONT VIEW K, L SIDE VIEW I, J, K, L

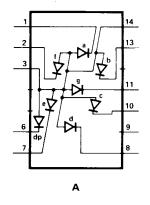
Package Dimensions (-3900/-4200 Series)

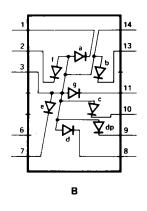


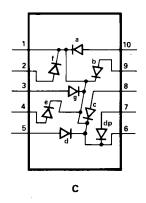
- 1. Dimensions in millimeters and (inches).
- 2. All untoleranced dimensions are for reference only.

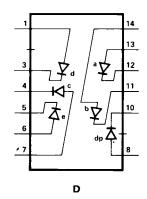
- 4. Unused dp position.
- 7. For HDSP-4030/-4130/-5731/-4200 Series product only. 5. See Internal Circuit Diagram. 8. See part number table for LHDP and RHDP designation.
- 6. Redundant Cathodes.

Internal Circuit Diagram (HDSP-3530/-4030 Series)

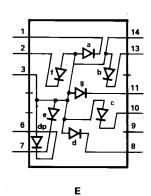


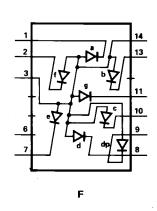


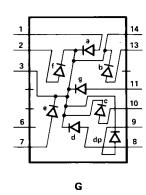


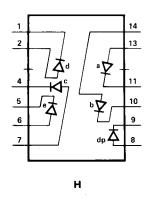


Internal Circuit Diagram (HDSP-3730/-4130 Series)

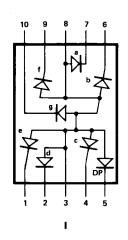


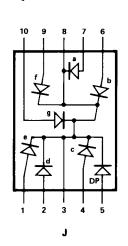


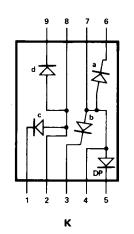


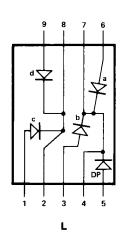


Internal Circuit Diagram (HDSP-5530/-5730 Series)

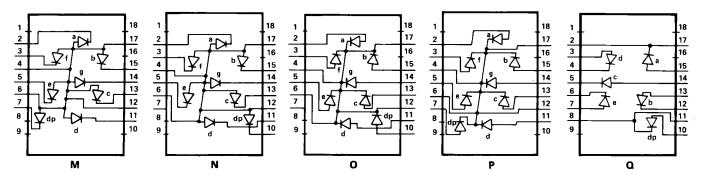








Internal Circuit Diagram (HDSP-3900/-4200 Series)



Electrical/Optical Characteristics at $T_A=25\,^{\circ}\mathrm{C}$

		Device					
Parameter	Sym.	HDSP-	Min.	Тур.	Max.	Units	Test Condition
Luminous Intensity/	$I_{\rm V}$	3530	1500	4500		μcd	100 mA Pk;
Segment ^[9,10]		3730	1500	5000			1 of 5 Duty Factor
(Digit Average)		5530	2200	7000			
		3900	2200	7000			
		3530		3100		μcd	20 mA DC
		3730		3500			
		5530		4800			
		3900		4800			
		4030	1500	4500		μcd	100 mA Pk;
		4130	1500	5000			1 of 5 Duty Factor
		5730 4200	2200	7000 7000			
			2200			1	90 A DC
		4030 4130		2200 2500		μcd	20 mA DC
		5730		3400			
		4200		3400			
Peak Wavelength	$\lambda_{ ext{PEAK}}$	3530/3730/		635		nm	
reak wavelengur	PEAK	5530/3900		000		11111	
		4030/4130/		583		nm	
		5730/4200		000		THE	
Dominant Wavelength ^[11,12]	$\lambda_{ m d}$	3530/3730/		626		nm	
(Digit Average)	, •u	5530/3900		0_0		1111	
		4030/4130/	581.5	586	592.5	nm	
		5730/4200					
Forward Voltage/Seg or D.P.	$V_{ m F}$	All Devices		2.6	3.5	V	$I_{\rm F} = 100 {\rm mA}$
Reverse Current/Seg or D.P.	I_{R}	All Devices			100	μA	$V_{R} = 3.0 \text{ V}$
Temp. Coeff. of V _F /Seg or D.P.	ΔV_F /°C	All Devices		-1.1		mV/°C	$I_{\rm F} = 100 {\rm mA}$
Thermal Resistance	$R\theta_{J-PIN}$	3530/4030/		282		°C/W/Seg	
LED Junction-to-Pin		3730/4130					
		5530/5730		345		°C/W/Seg	
		3900/4200		375		°C/W/Seg	

Notes

- 9. Case temperature of the device immediately prior to the intensity measurement is 25° C.
- 10. The digits are categorized for luminous intensity with the intensity category designated by a letter on the side of the package.
- 11. The dominant wavelength, l_d , is derived from the CIE chromaticity diagram and is that single wavelength which defines the color of the device.
- 12. The yellow displays are categorizes as to dominant wavelength with the category designated by a number adjacent to the intensity category letter.

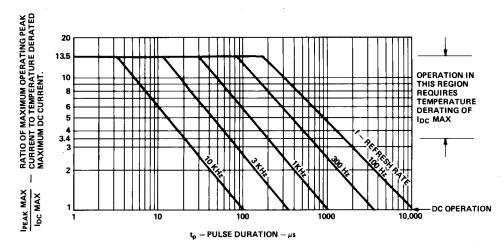


Figure 1. Maximum Allowed Peak Current vs. Pulse Duration.

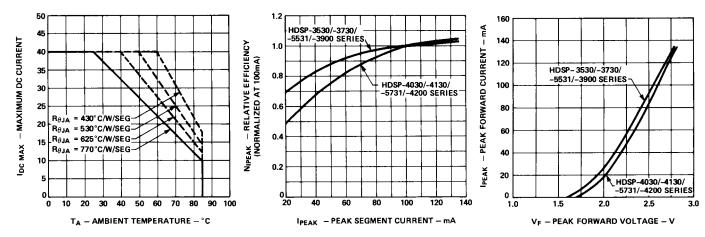


Figure 2. Maximum Allowable DC Current per Segment vs. Ambient Temperature.

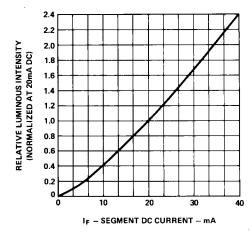


Figure 5. Relative Luminous Intensity vs. DC Forward Current.

Figure 3. Relative Efficiency (Luminous Intensity per Unit Current) vs. Peak Segment Current.

Electrical

These display devices are composed of eight light emitting diodes, with light from each LED optically stretched to form individual segments and a decimal point.

The devices utilize LED chips which are made from GaAsP on a transparent GaP substrate.

These display devices are designed for strobed operation. The typical forward voltage values, scaled from Figure 4, should be used for calculating the current limiting resistor value and typical power dissipation.

Figure 4. Peak Forward Segment Current vs. Peak Forward Voltage.

Expected maximum V_F values, for the purpose of driver circuit design and maximum power dissipation, may be calculated using the following V_F MAX models:

$$V_F MAX = 2.15 V + I_{PEAK} (13.5 \Omega)$$

For: $I_F \ge 30 \text{ mA}$

$$V_F \text{ MAX} = 1.9 \text{ V} + I_{DC} (21.8 \Omega)$$

For: 10 mA \le $I_F \le 30$ mA

Temperature derated strobed operating conditions are obtained from Figures 1 and 2. Figure 1 relates pulse duration (t_p) , refresh rate (f), and the ratio of maximum peak current to maximum

dc current (I_{PEAK} MAX/ I_{DC} MAX). Figure 2 presents the maximum allowed dc current vs. ambient temperature. Figure 1 is based on the principle that the peak junction temperature for pulsed operation at a specified peak current, pulse duration and refresh rate should be the same as the junction temperature at maximum DC operation. Refresh rates of 1 kHz or faster minimize the pulsed junction heating effect of the device resulting in the maximum possible time average luminous intensity.

The time average luminous intensity can be calculated knowing the average forward current and relative efficiency characteristic, $\eta_{|PEAK}$, of Figure 3. Time average luminous intensity for a device case temperature of 25°C, I_V (25°C), is calculated as follows:

$$I_{V}\left(25^{\circ}\mathrm{C}\right) = \left[\frac{I_{AVG}}{20~\mathrm{mA}}\right] \left[\eta_{|\mathrm{PEAK}}\right] \left[I_{V~\mathrm{DATA~SHEET}}\right]$$

Example: For HDSP-4030 series

$$\eta_{\,|\mathrm{PEAK}}=1.00$$
 at $I_{\mathrm{PEAK}}=100$ mA. For DF = 1/5:

$$I_V (25^\circ) = \left[\frac{20 \text{ mA}}{20 \text{ mA}}\right] [1.00][4.5 \text{ mcd}]$$

= 4.5 mcd/segment

The time average luminous intensity may be adjusted for operating junction temperature by the following exponential equation:

$$I_V(T_J) = I_V(25^{\circ}C) e^{[k(T_J + 25^{\circ}C)]}$$

where
$$T_J = T_A + P_D \cdot R\theta_{J-A}$$

Device	K
-3530/-3730/	-0.0131/°C
-5530/-3900	
-4030/-4130/	-0.0112/°C
-5730/-4200	

Mechanical

These devices are constructed utilizing a lead frame in a standard DIP package. The LED dice are attached directly to the lead frame. Therefore, the cathode leads are the direct thermal and mechanical stress paths to the LED dice. The absolute maximum allowed junction temperature, T_J MAX, is 105° C. The maximum power ratings have been established so that the worst case V_F device does not exceed this limit.

Worst case thermal resistance pin-to-ambient is 400°C/W/Seg when these devices are soldered into minimum trace width PC boards. When installed in a PC board that provides $R\theta_{PIN-A}$ less than 400°C/W/Seg these displays may be operated at higher average currents as shown in Figure 2.

Optical

The radiation pattern for these devices is approximately Lambertian. The luminous sterance may be calculated using one of the two following formulas.

$$L_{V}(cd/m^{2}) = \frac{I_{V}(cd)}{A(m^{2})}$$

$$L_V(footlamberts) = \frac{\pi I_V(cd)}{A(ft^2)}$$

Area/Seg. Area/Seg. $\rm mm^2$ in^2 Device 3530/-4030 0.0039 2.5-3730/-4130 0.0068 4.4 -5530/-5730 8.8 0.0137 -3900/-4200 14.9 0.0231

Contrast Enhancement

The objective of contrast enhancement is to optimize display readability. Adequate contrast enhancement can be achieved in indoor applications through luminous contrast techniques. Luminous contrast is the observed brightness of the illuminated segment compared to the brightness of the surround. Appropriate wavelength filters maximize luminous contrast by reducing the amount of light reflected from the area around the display while transmitting most of the light emitted by the segment. These filters are described further in Application Note 1015.

Chrominance contrast can further improve display readability. Chrominance contrast refers to the color difference between the illuminated segment and the surrounding area. These displays are assembled with a gray package and untinted encapsulating epoxy in the segments to improve chrominance contrast of the ON segments. Additional contrast enhancement in bright ambients may be achieved by using a neutral density gray filter such as Panelgraphic Chromafilter Gray 10, or 3M Light Control Film (louvered film).